

SSCE4V5X2L2 Series

High Power TVS Diode

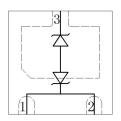
Description

The SSCE4V5X2L2 is a high power TVS, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive lines. The SSCE4V5X2L2 Series complies with the IEC 610002 (ESD) standard with $\pm 30 \mathrm{kV}$ air and $\pm 30 \mathrm{kV}$ contact discharge. It is assembled into a 3pin DFN20203 package. The leads are finished with NiPdAu. Each device will protect one line. The combination of small size, and high surge capability makes them ideal for use in applications such as cellular phones, LCD displays, USB, and multimedia card interfaces.

Feature

- \Rightarrow 2000W, 5000W peak pulse power (TP = 8/20 μ s)
- ♦ DFN2020 Package
- ♦ Working voltage: 4.5V
- ♦ Low clamping voltage
- ♦ Low capacitance
- ♦ RoHS compliant transient protection for high speed data lines to IEC61000-4-2(ESD)±15kV(air),±8kV(contact)

PIN configuration



Topview

Applications

- ♦ DVI & HDMI Port Protection
- ♦ Serial and Parallel Ports
- ♦ Projection TV
- ♦ Notebooks, Desktops, Server
- ♦ Solid-state Punch-Through TVS Process technology Portable instrumentation

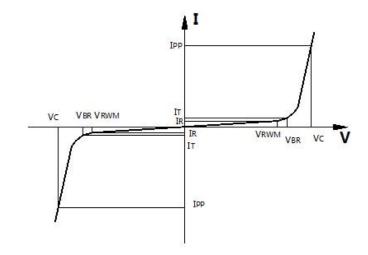
Machanical data

- ♦ Lead finish:100% matte Sn(Tin)
- ♦ Mounting position: Any
- ♦ Power Supply Protection
- ♦ Industrial Application



• Electronic Parameter

Symbol	Parameter		
V_{RWM}	Peak Reverse Working Voltage		
I_R	Reverse Leakage Current @ V _{RWM}		
V_{BR}	Breakdown Voltage @ I _T		
I _T	Test Current		
I_{PP}	Maximum Reverse Peak Pulse Current		
Vc	Clamping Voltage @ IPP		
P _{PP}	Peak Pulse Power		
С	Junction Capacitance		



Absolute maximum rating @TA=25°C

Symbol	Parameter	Value	Units
P _{PP}	Peak Pulse Power (8/20µS)	2000, 5000W	W
T _{STG}	Storage Temperature	-55/+150	$^{\circ}$
T _J	Operating Temperature	-55/+150	$^{\circ}$

• Electrical Characteristics @TA=25°C

		V_{RWM}	I _{R@}	V _{BR@} 1mA	V_{CI}	IPP@8/20μs	Capacitance	P _{Pk}
Device	Marking VRWM		V_{RWM}	(Volts)	@50A	(Amps)	@V _R =0V,1MHz(pF)	
		(V)	(uA)	Min	(V)	Max.	Тур	(W)
SSCE4V512L2	4.5H	4.5	1	5	5	180	800	2000
SSCE4V522L2	4.5H	4.5	1	5	6	350	800	5000



• Typical Performance Characteristics

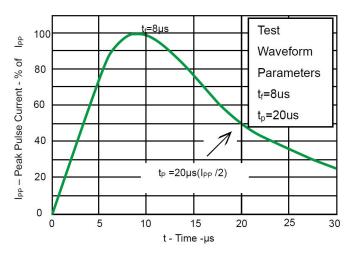


Fig 1.Pulse Waveform

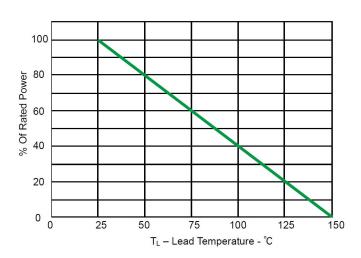
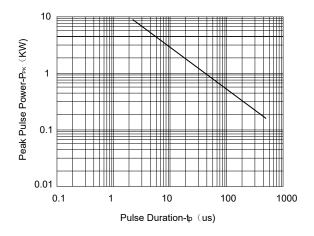


Fig 2.Power Derating Curve

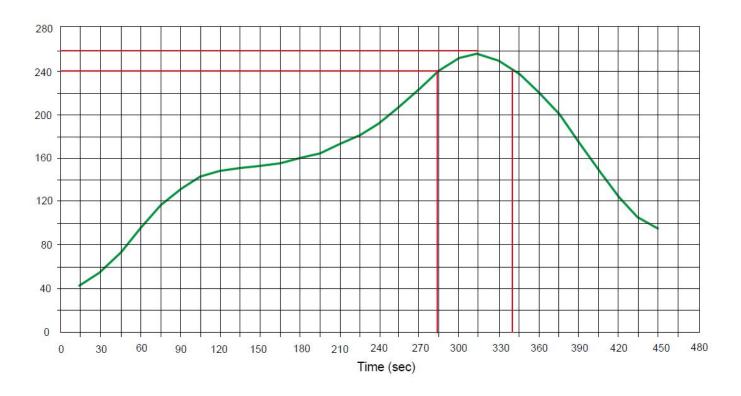


Non-Repetitive Peak Pulse Power vs. Pulse Time



• Solder Reflow Recommendation

Peak Temp=257°C, Ramp Rate=0.802deg. °C/sec





Package Information

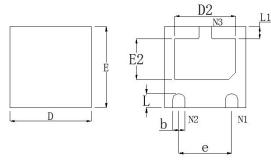
Ordering Information

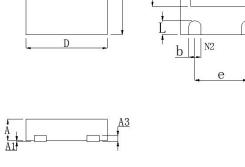
Device	Package	Qty per Reel	Reel Size	
SSCE4V5X2L2	DFN2020-3L	3000	7 Inch	

Mechanical Data

Case: DFN2020

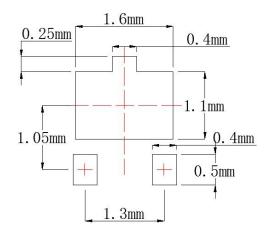
Case Material: Molded Plastic. UL Flammability





DIM	Millimeters				
DIM	Min	Nom	Max		
A	0.50	0. 55	0.60		
A1	0.00	-	0.05		
A3	0.15 REF.				
D	1. 95	2.00	2.05		
Е	1. 95	2.00	2.05		
b	0. 25	0.30	0. 35		
L	0.30	0.35	0.40		
L1	0. 25	0.30	0.35		
D2	1. 35	1. 50	1.60		
E2	0.85	1.00	1. 10		
е	1.30 BSC				

Recommended Pad outline





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